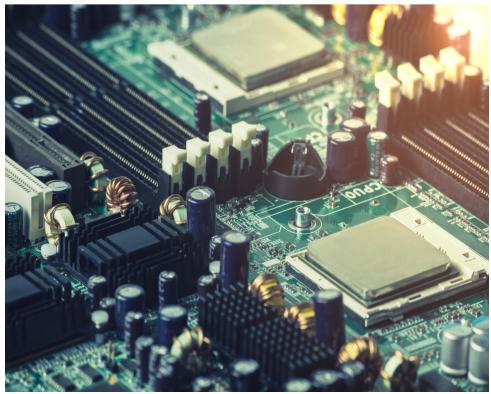
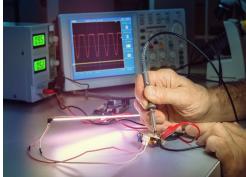
Model 675 | 300 MHz 1.2 GS/s

High Performance Arbitrary Waveform Generator and Data Pattern Generator









Features

- 2, 4 or 8 Analog Channels
- 1.2 GS/s, 14-bit Vertical Resolution
- 300 MHz Bandwidth
- Up to 24 Vp-p Output Voltage and ± 12 V Baseline Offset
- Up to 128 Mpts Waveform Memory per Channel
- Up to 32 Digital Channels in Synchronous with Analog Generation

Applications

- Aerospace and Defense
- Institute and University Research
- Semiconductor Tests
- Automotive
- IoT



Model 675 | 300 MHz 1.2 GS/s Arbitrary Waveform Generator





Description

The Model 675 is a simple-to-use arbitrary waveform generator that operates on Windows 10 via the TrueArb interface, an intuitive proprietary GUI. TrueArb can easily be navigated via the touch screen or via remote communication supported through a standard Ethernet interface.

The Model 675 comes with a 300MHz arbitrary frequency generator and up to 8 analog channels operating up to 12 Vpp into 50 Ω load impedance. An 32 digital output option is also available with each digital output providing up to a 1.2 Gb/s data rate in LVDS output format. The Model 675 also boasts a 1 S/s (Sample/second) to 1.2 GS/s with 14-bit vertical resolution, providing outstanding signal integrity with a rise time/fall time of less than 2 ns.



Digital output, combined and synchronized with analog output signals, is an ideal diagnostic tool for digital designs. The Model 675 can produce waveforms with a memory length of up to 128 Mpoints on each channel, combined with up to 16,384 sequences and 4,294,967,294 repetitions, making it the ideal generator for the most demanding technical applications.

Model 675 Front



Model 675 Back

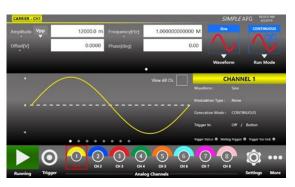






Model 675 User Interface Simple Rider AFG: Function Generator Mode Interface

Simple Rider AFG UI is designed for touch and it has been developed to put all the capabilities of modern Waveform Generators right at your fingertips. All instrument controls and parameters are accessed through an intuitive UI that recalls the simplicity of Tablets and modern smart phones: touch features and gestures are available to engineers and scientists to create advanced waveforms or digital patterns in few touches.



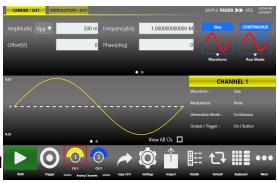
- · The swipe gesture gives easy access to the output waveform parameters
- A touch-friendly virtual numeric keypad has been designed to improve the user experience on entering the data.
- Time saving shortcuts and intuitive icons simplify the instrument setup.

Simple Rider TrueArb: AWG and DPG Mode Interface

In **Simple Rider TrueArb** interface, the users can define complex waveforms with up to 16,384 sequence entries of analog waveforms and digital patterns, define their execution flow by means of loops, jumps and conditional branches.

Digital output combined and synchronized with analog output signals represent an ideal tool to troubleshoot and validate digital design. The waveform memory length of up to 4 GSamples on each channel combined with up to 16,384 and up to 4,294,967,294 repetitions, make the Model 675 the ideal generator for the most demanding technical applications.

Thanks to the intuitive and easy waveform sequencer user interface, the most complex waveform scenarios can be created with just few screen touches.











Simple Rider SPG: Serial Pattern Generator (SPG) Mode Interface

The easiest touch screen display interface allows to create patterns scenarios, only in a few screen touches. In summary the Data Pattern Generator provides the capability to generate PRBS patterns and up to 2MSymbols custom patterns where bit transitions can have arbitrarily user defined shapes. The Model 675 Serial Pattern Generator can generate patterns up to 300Mbaud.





The software architecture provides the possibility to easily generate the patterns in different generation modality and also gives the opportunity to modulate the patterns with internal or external signals with the purpose to generate also different effects of noise (jitter, ripple, ...).





Model 675 Applications

Automotive

Today's cars are including a lot of highly sophisticated electronic control unit with very sensitive electronic components. The Model 675 combining 1.2 GSa/s with 14-bit vertical resolution, represents an ideal tool for successfully addressing the new testing challenges in automotive.

- CAN, CAN-FD,LIN, Flexray,SENT emulation
- EMI debugging, troubleshooting, and testing
- Electrical standards emulation up to 24V
- Power MOSFET circuitry in automotive electronics optimization



IoT and Ind 4.0 Perfect RF Modulator

The Model 675 will be the iconic instrument for this application. The possibility to emulate complex RF I/Q modulation for simulation and Test vs wireless devices or working on Internet of things of industry 4.0 applications. Each engineer may use the possibility to import waveform to emulate devices under test, impose distortion on waveform (such noise) to test the ability of devices to be compliant to the standards.



Semiconductor Testing

Emulation of complex signals generated with inclusion of noise or distortions may became an excellent way to provide Compliance Components Test to help semiconductors engineers. The fast edges and pulse generation can be used to provide characterization in fast power devices.





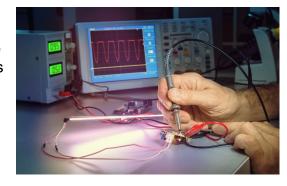




Research Applications

Research centers and universities are key users of the Model 675, which can produce complex waveforms, multilevel signals, and pulse emulation based on variable edges. The Model 675's combination of fast edge generation, excellent dynamic range and simple user interface meets the demands of scientists and engineers working on intensive experiments such as accelerators, tokamak, or synchrotrons, to emulate signals without creating specifics test boards.

- Emulation of detectors
- Emulation of signal sources adding noise
- · Generation/playback of real-world signals
- Emulation of long PRBS sequences
- Modulating and driving laser diode



Aerospace and Defense applications

The Model 675 works perfectly with electronic warfare signals, such as those produced by Radar or Sonar systems. This generator can also be fitted into a modular system for radio or I/Q signal modulation, as well as create pulses useful in applications such as pulse electron beams, X-ray sources, flash X-ray radiography, lightning pulse simulators, and high power microwave modulators.

- Frequency response, intermodulation distortion and noise-figure measurements
- Phase Locked Loop (PLL) pull-in and hold range characterization
- Radar base-band signals emulation











Model 675 Specifications
All specifications are typical unless noted otherwise. The guaranteed performances are referred to a calibrated instrument that has been stored for a minimum of 2 hours within the operating temperature range of 5°C to 40°C and after a 45-minute warm up period. Within ±10°C after auto-calibration

Number of Channels	Model 675-2C	Model 675-4C	Model 675-8C
Analog	2	4	8
Digital Out	0/8 optional	0/8/16 optional	0/8/16/32 optiona
Marker Out	1	2	4
Operating Mode	AFG Mode True Arb Mode Data Pattern Generat	or	
Amplitude			
Range (50 Ω into 50 Ω) ¹	0 to 6V _{p-p} (12 V _{p-p} opti	onal)	
Accuracy (1kHz sine wave, 0V offset, > 5mV _{p-p} amplitude, 50Ω load) (guaranteed)	±(1% of setting [V _{p-p}] -	+ 5 mV)	
Resolution	<0.5 mV _{p-p} or 5 digits		
Output impedance	Single-ended: 50 Ω, L	ow Impedance: 5 Ω	
Baseline Offset	<u>'</u>		
Range (50 Ω into 50 Ω)	-3 V to +3 V (-6V to +6	6V opt.)	
Range (50 Ω into High Z load)	-6 V to +6 V (-12V to	+12V opt.)	
Accuracy (50 Ω into 50 Ω) (guaranteed)	±(1% of setting ±5 m	V)	
Resolution	<4 mV or 4 digits		
DC			
Amplitude range (50 Ω, single-ended)	-3V to 3V (-6V to 6V c	opt.)	
Amplitude accuracy (guaranteed)	±(1% of setting + 10	mV)	
AFG Mode Specifications			
Output Channels			
Connectors	BNC on front panel		
Output type	Single-ended		
Output Impedance	50 Ω or 5 Ω (low impe	edance)	
General Specifications		·	
Operating mode	DDS mode		
Standard Waveforms		Ramp, more (Noise, DC, Rise, Exponential Decay,	. , .
Run Modes	Continuous, modulation	on, sweep, burst	
Arbitrary Waveforms	Vertical resolution: 14		
	Waveform length: 16,	384 points	
Internal Trigger Timer Range	13.3 ns to 100 s		
Resolution	104 ps		
Accuracy	±(0.1% setting + 5 ps))	

¹ Amplitude doubles on HiZ load







Sine Waves	
Frequency Range Sine (50 Ω into 50 Ω) ²	1 μHz to ≤ 70 MHz: 12V
	>70 MHz to ≤120 MHz: 9V
	>120 MHz to ≤180 MHz: 6V
	>180 MHz to ≤300 MHz: 3V
	(without HV opt. the maximum amplitude is limited to 6 V)
Flatness (1 Vp-p, relative to 1 kHz)	DC to 300 MHz: ±0.5 dB
Harmonic Distortion (1 V _{p-p})	1 μHz to ≤ 10 MHz: < -65 dBc
	> 10 MHz to ≤ 50 MHz: < -55 dBc
	> 50 MHz to ≤ 100 MHz: < -45 dBc
	> 100 MHz to ≤ 300 MHz: < -30 dBc
Total Harmonic Distortion (1 V _{p-p})	10 Hz to 20 kHz: < 0.1%
Spurious (1 V_{p-p}) (excluding f_{Sa} - f_{out} , f_{Sa} - $2*f_{out}$)	1 μHz to ≤ 10 MHz: < -60 dBc
	>10 MHz to ≤ 300 MHz: < -55 dBc
Phase Noise (1 V _{p-p} , 10 kHz offset)	10 MHz: < -120 dBc/Hz typ.
	100 MHz: < -115 dBc/Hz typ.
Square Waves	
Frequency Range	1 μHz to ≤ 40 MHz: 12V
	>40 MHz to ≤80 MHz: 10V
	>80 MHz to ≤150 MHz: 7V (without HV opt. the maximum amplitude is limited to 6 V)
Rise/fall time	2 ns
<u> </u>	
Overshoot (1 V _{p-p})	< 2%
Jitter (rms)	< 20 ps
Pulse Waves	
Frequency Range	1μHz to ≤ 5 MHz: 12V
	>5 MHz to ≤60 MHz: 10V
	>60 MHz to <150 MHz: 7V
Dode - WE-III	(without HV opt. the maximum amplitude is limited to 6 V)
Pulse Width	2.5 ns to (Period – 2.5 ns)
Pulse Width Resolution	20 ps or 15 digits
Pulse Duty Cycle	0% to 100%, 14 digits (limitations of pulse width apply)
Leading/trailing edge transition time	2 ns to 1000 s
Transition time Resolution	2 ps or 15 digits
Overshoot (1 V _{p-p})	< 2%
Jitter (rms, with rise and fall time ≥ 2 ns)	< 20 ps
Double Pulse Waves	
Frequency Range	Without HV option :
	1μHz to ≤ 5 MHz: 12 V _{p-p}
	>5 MHz to ≤150 MHz: 6 V _{p-p}
	where $V_{p-p} = V_{p-p} 1 + V_{p-p} 2 $
	With HV option:
	1 μHz to ≤ 5 MHz: 24 V _{P-P} >5 MHz to ≤60 MHz: 10 V _{P-P}
	>5 MHz to ≤00 MHz. 10 V _{p-p} >60 MHz to ≤150 MHz: 7 V _{p-p}
	where $V_{p-p} = V_{p-p} 1 + V_{p-p} 2 $
Other Pulse Parameters	Same as Pulse Waves
Ramp Waves	
Frequency Range	1 μHz to 15 MHz
CIEUDEUCV DAUDE	LI ULIZ IU 13 MITZ

² Amplitude doubles on HiZ load









Symmetry O% to 100%	Linearity (< 10 kHz, 1 V _{p-p} , 100%)	≤ 0.1%
Prequency Range		0% to 100%
Exponential Rise, Exponential Decay 1 µHz to 30 MHz 3 µHz to 30 MHz to 30 MHz 3 µHz to 30 MHz 3 µHz to 30 MHz	Other Waves	
Sin(x) x, Gaussian, Lorentz, Haversine 1 μHz to 30 MHz	Frequency Range	
Additive Noise Bandwidth (-3 dB) Level Resolution 1 mV Arbitrary Number of Samples 2 to 16,384 Frequency range 1 μHz to ≤ 150 MHz Analog Bandwidth (-3 dB) 175 MHz Rise/Fall Time 2 ns Jitter (ms) 3 c 20 ps Frequency Resolution Frequency Resolution Sine, square, pulse, arbitrary, Sin(x)/x Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine Frequency Accuracy Non-ARB 2 to x 10° of setting ARB 2 to x 10° of setting ±1 μHz Modulation Source Internal Modulating Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal Modulation (FM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal Modulation (FM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal Modulation (FM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal Modulation (FM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal Modulation (FM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal Modulation (FM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal Modulation (FM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal Modulation (FM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal Modulation (FM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal Modulation (FM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal Modulation Source Internal Modulation Source Internal Modulation Source Internal Source (except Pulse, DC and Noise), ARB Modulation Source Internal Source (except Pulse, DC and Noise), ARB Modulation Source Interna		·
Bandwidth (-3 dB) 200 MHz 0 V to 6 V − carrier max value [V _μ] Resolution 1 mV 1 mV		1 μHz to 30 MHz
Level Resolution 0 Y to 6 V − carrier max value [V _{pt}] 1 mV Arbitrary Number of Samples 2 to 16,384 Frequency range 1 μHz to s 150 MHz Analog Bandwidth (-3 dB) 175 MHz Rise/Fall Time 2 ns Jitter (rms) < 20 ps		. 000 MH-
Arbitrary	, ,	
Arbitrary Number of Samples 2 to 16,384 Frequency range 1 μHz to ≤ 150 MHz Analog Bandwidth (-3 dB) 175 MHz Rise/Fall Time 2 ns Jitter (ms) < 20 ps		
Frequency range	Arbitrary	
Analog Bandwidth (-3 dB) 175 MHz Rise/Fall Time 2 ns Jitter (rms) < 20 ps Frequency Resolution Sine, square, pulse, arbitrary, Sin(x)/x 1 µHz or 15 digits Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine Frequency Accuracy Non-ARB ±2.0 x 10° of setting ARB ±2.0 x 10° of setting ARB ±2.0 x 10° of setting ARB ±2.0 x 10° of setting ±1 µHz Modulations Amplitude Modulation (AM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal or external Internal Modulating Waveforms Sine, Square, Ramp, Noise, ARB Modulation Frequency Internal: 8 MHz maximum Depth 0.00% to 120.00% Frequency Modulation (FM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulating Frequency Internal: 8 MHz maximum Depth 0.00% to 120.00% Frequency Modulation (FM) Carrier Maveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulating Source Internal or external Internal Modulating Waveforms Sine, Square, Ramp, Noise, ARB Modulating Frequency Internal: 8 MHz maximum Peak Deviation Dc to 300 MHz External: 8 MHz maximum Peak Deviation PM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal: 8 MHz maximum Phase Modulation (PM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal: 600 µHz to 48 MHz External: 8 MHz maximum Phase Modulating Waveforms Sine, Square, Ramp, Noise, ARB Modulation Source Internal Fool µHz to 48 MHz External: 8 MHz maximum Phase Deviation Range Internal: 500 µHz to 48 MHz External: 8 MHz maximum Phase Deviation Range Internal: 500 µHz to 48 MHz External: 8 MHz maximum Phase Deviation Range Internal: 500 µHz to 48 MHz External: 8 MHz maximum Phase Deviation Range Internal: 500 µHz to 48 MHz External: 8 MHz maximum Phase Deviation Range Internal: 500 µHz to 48 MHz External: 8 MHz maximum Phase Deviation Range Internal: 500 µHz to 48 MHz External: 8 MHz maximum Phase Deviation Range Internal: 500 µH	Number of Samples	2 to 16,384
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Jitter (rms) < 20 ps	Analog Bandwidth (-3 dB)	175 MHz
Frequency Resolution Sine, square, pulse, arbitrary, Sin(x)/x 1 μHz or 15 digits Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine 1 μHz or 14 digits Frequency Accuracy Non-ARB ±2.0 x 10 ° of setting ARB ±2.0 x 10 ° of setting ±1 μHz Modulations Amplitude Modulation (AM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal or external Internal Modulating Waveforms Sine, Square, Ramp, Noise, ARB Modulating Frequency Internal: 500 μHz to 48 MHz External: 8 MHz maximum External: 8 MHz maximum Depth 0.00% to 120.00% Frequency Modulation (FM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal or external Internal Modulating Waveforms Sine, Square, Ramp, Noise, ARB Modulation Frequency Internal: 500 μHz to 48 MHz External: 8 MHz maximum External: 8 MHz maximum Phase Modulation (PM) Standard waveforms (except Pulse, DC and Noise), ARB <	Rise/Fall Time	2 ns
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Non-ARB		1 μHz or 14 digits
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External: 8 MHz maximum Depth 0.00% to 120.00% Frequency Modulation (FM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal or external Internal Modulating Waveforms Sine, Square, Ramp, Noise, ARB Modulating Frequency Internal: 500 μHz to 48 MHz External: 8 MHz maximum Peak Deviation DC to 300 MHz Phase Modulation (PM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal or external Internal Modulating Waveforms Sine, Square, Ramp, Noise, ARB Modulating Frequency Internal: 500 μHz to 48 MHz External: 8 MHz maximum Phase Deviation Range 0° to 360° Frequency Shift Keying (FSK) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB	Internal Modulating Waveforms	Sine, Square, Ramp, Noise, ARB
Frequency Modulation (FM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal or external Internal Modulating Waveforms Sine, Square, Ramp, Noise, ARB Modulating Frequency Internal: 500 μHz to 48 MHz External: 8 MHz maximum DC to 300 MHz Phase Modulation (PM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal or external Internal Modulating Waveforms Sine, Square, Ramp, Noise, ARB Modulating Frequency Internal: 500 μHz to 48 MHz External: 8 MHz maximum External: 8 MHz maximum Phase Deviation Range 0° to 360° Frequency Shift Keying (FSK) Standard waveforms (except Pulse, DC and Noise), ARB	Modulating Frequency	•
Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal or external Sine, Square, Ramp, Noise, ARB Modulating Frequency Internal: 500 µHz to 48 MHz External: 8 MHz maximum Peak Deviation DC to 300 MHz Phase Modulation (PM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal or external Internal Modulating Waveforms Sine, Square, Ramp, Noise, ARB Modulating Frequency Internal: 500 µHz to 48 MHz External: 8 MHz maximum Phase Deviation Range O° to 360° Frequency Shift Keying (FSK) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB	Depth	0.00% to 120.00%
Modulation Source Internal or external Internal Modulating Waveforms Sine, Square, Ramp, Noise, ARB Modulating Frequency Internal: 500 µHz to 48 MHz External: 8 MHz maximum Peak Deviation DC to 300 MHz Phase Modulation (PM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal or external Internal Modulating Waveforms Sine, Square, Ramp, Noise, ARB Modulating Frequency Internal: 500 µHz to 48 MHz External: 8 MHz maximum Phase Deviation Range 0° to 360° Frequency Shift Keying (FSK) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB	Frequency Modulation (FM)	
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Modulating Frequency Internal: 500 μHz to 48 MHz External: 8 MHz maximum Peak Deviation DC to 300 MHz Phase Modulation (PM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal or external Internal Modulating Waveforms Sine, Square, Ramp, Noise, ARB Modulating Frequency Internal: 500 μHz to 48 MHz External: 8 MHz maximum Phase Deviation Range 0° to 360° Frequency Shift Keying (FSK) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB	Modulation Source	Internal or external
External: 8 MHz maximum Peak Deviation DC to 300 MHz Phase Modulation (PM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal or external Internal Modulating Waveforms Sine, Square, Ramp, Noise, ARB Modulating Frequency Internal: 500 µHz to 48 MHz External: 8 MHz maximum Phase Deviation Range 0° to 360° Frequency Shift Keying (FSK) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB	Internal Modulating Waveforms	Sine, Square, Ramp, Noise, ARB
Peak Deviation DC to 300 MHz Phase Modulation (PM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal or external Internal Modulating Waveforms Sine, Square, Ramp, Noise, ARB Modulating Frequency Internal: 500 μHz to 48 MHz External: 8 MHz maximum Phase Deviation Range 0° to 360° Frequency Shift Keying (FSK) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB	Modulating Frequency	·
Phase Modulation (PM) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal or external Internal Modulating Waveforms Sine, Square, Ramp, Noise, ARB Modulating Frequency Internal: 500 µHz to 48 MHz External: 8 MHz maximum Phase Deviation Range 0° to 360° Frequency Shift Keying (FSK) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB		
Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB Modulation Source Internal or external Internal Modulating Waveforms Sine, Square, Ramp, Noise, ARB Modulating Frequency Internal: 500 µHz to 48 MHz External: 8 MHz maximum Phase Deviation Range 0° to 360° Frequency Shift Keying (FSK) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB		DC to 300 MHz
Modulation Source Internal or external Internal Modulating Waveforms Sine, Square, Ramp, Noise, ARB Modulating Frequency Internal: 500 µHz to 48 MHz External: 8 MHz maximum Phase Deviation Range 0° to 360° Frequency Shift Keying (FSK) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB	,	Chandard was of sure (sure of Dulas, DC and Nairs) ADD
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Modulating Frequency Internal: 500 μHz to 48 MHz External: 8 MHz maximum Phase Deviation Range 0° to 360° Frequency Shift Keying (FSK) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB		
External: 8 MHz maximum Phase Deviation Range 0° to 360° Frequency Shift Keying (FSK) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB		
Phase Deviation Range 0° to 360° Frequency Shift Keying (FSK) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB	woulding riequency	
Frequency Shift Keying (FSK) Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB	Phase Deviation Range	
Carrier Waveforms Standard waveforms (except Pulse, DC and Noise), ARB		
Modulation Source Internal or external		Standard waveforms (except Pulse, DC and Noise), ARB
	Modulation Source	Internal or external







Internal Modulating Waveforms	Square
Key Rate	Internal: 500 µHz to 48 MHz
	External: 8 MHz maximum
Hop Frequency	1 μHz to 300 MHz
Number of Keys	2
Phase Shift Keying (PSK)	
Carrier Waveforms	Standard waveforms (except Pulse, DC and Noise), ARB
Modulation source	Internal or external
Internal Modulating Waveforms	Square
Key Rate	Internal: 500 µHz to 48 MHz
	External: 8 MHz maximum
Hop Frequency	0° to +360°
Number of Keys	2
Pulse Width Modulation (PWM)	
Carrier Waveforms	Pulse
Modulation Source	Internal or external
Internal Modulating Waveforms	Sine, Square, Ramp, Noise, ARB
Modulating Frequency	Internal: 500 µHz to 48 MHz
	External: 8 MHz maximum
Deviation Range	0% to 50% of pulse period
Sweep	
Туре	Linear, Logarithmic, staircase, and user defined
Waveforms	Standard waveforms (except Pulse, DC and Noise), ARB
Sweep Time	40 ns to 2000 s
Hold/return Times	0 to (2000 s - 40 ns)
Sweep/Hold/Return Time Resolution	20 ns or 12 digits
Total Sweep Time Accuracy	≤ 0.4%
Start/Stop Frequency Range	Sine: 1 μHz to 300 MHz, Square: 1 μHz to 150 MHz
Trigger Source	Internal (Timer) / External / Manual
Burst	
Waveforms	Standard waveforms (except DC and Noise), ARB
Туре	Trigger or gated
Burst Count	1 to 4,294,967,295 cycles or Infinite
True Arb Mode Specifications	
Output Channels	
Connectors	BNC on front panel
Output Type	Single-ended
Output Impedance	50 Ω or 5 Ω (low impedance)
General specifications	
Operating Mode	Variable clock (True Arbitrary)
Run Modes	Continuous, Triggered Continuous,
	Circula / Dunat Channad Advanced

Single/Burst, Stepped, Advanced

16 to 2M samples per channel (675-XC-2M) 16 to 64M samples per channel (675-XC-64M) 16 to 128M samples per channel (675-XC-128M)

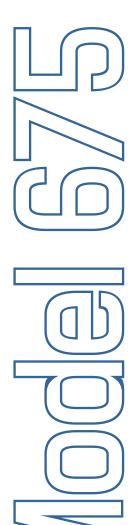
14 bit

where X = 2,4 or 8

Vertical Resolution

Waveform Length





Waveform Granularity	1 if the entry length is >384 samples
	16 if entry length is ≥32 and ≤384 samples
Sequence Length	1 to 16,384
Sequence Repeat Counter	1 to 4,294,967,295 or infinite
Timer	
Range	23.52 ns to 7 s
Resolution	±1 sampling clock period
Analog Channel to Channels skew	
Range	0 to 3.4 us
Resolution	≤ 5 ps
Accuracy	±(1% of setting + 20 ps)
Initial skew	< 200 ps
Calculated bandwidth (0.35 / rise or fall time)	≥ 318 MHz
Harmonic distortion (Sine wave 32 pts, 1 V _{p-p})	< -60 dBc (@ 1.2 GS/s, 37.5 MHz)
Spurious (Sine wave 32 pts, 1 V _{p-p}	< -60 dBc (@ 1.2 GS/s, 37.5 MHz)
SFDR (Sine wave 32 pts, 1 V _{p-p})	< -60 dBc (@ 1.2 GS/s, 37.5 MHz)
Rise/fall time (1 V _{p-p} single-ended 10% to 90%)	≤ 1.1 ns
Overshoot (1 V _{p-p} single-ended)	< 2%
Timing and Clock	
Sampling Rate	
Range	1 Sample/s to 1.2 GSample/s
Resolution	16 Hz
Accuracy	± 2.0 x 10 ⁻⁶
Random jitter on clock pattern (rms)	< 10 ps
Digital outputs (Optional)	10 ps
Output Channels	
Output Chaineis	
•	Mini CAC LID connector on room nonel
Connectors	Mini-SAS HD connector on rear panel
Connectors	(Non-standard pinout)
Connectors Number of connectors	(Non-standard pinout)
Connectors Number of connectors Number of outputs	(Non-standard pinout) 1 8-bits
Connectors Number of connectors Number of outputs Output impedance	(Non-standard pinout) 1 8-bits 100 Ω differential
Connectors Number of connectors Number of outputs Output impedance Output type	(Non-standard pinout) 1 8-bits 100 Ω differential LVDS
Connectors Number of connectors Number of outputs Output impedance Output type Rise/fall time (10% to 90%)	(Non-standard pinout) 1 8-bits 100 Ω differential LVDS < 1 ns
Connectors Number of connectors Number of outputs Output impedance Output type Rise/fall time (10% to 90%) Jitter (rms)	(Non-standard pinout) 1 8-bits 100 Ω differential LVDS < 1 ns 20 ps
Connectors Number of connectors Number of outputs Output impedance Output type Rise/fall time (10% to 90%) Jitter (rms) Maximum update rate	(Non-standard pinout) 1 8-bits 100 Ω differential LVDS <1 ns 20 ps 1.2 Gbps
Connectors Number of connectors Number of outputs Output impedance Output type Rise/fall time (10% to 90%) Jitter (rms)	(Non-standard pinout) 1 8-bits 100 Ω differential LVDS <1 ns 20 ps 1.2 Gbps 2M samples per channel (675-XC-2M)
Connectors Number of connectors Number of outputs Output impedance Output type Rise/fall time (10% to 90%) Jitter (rms) Maximum update rate	(Non-standard pinout) 1 8-bits 100 Ω differential LVDS < 1 ns 20 ps 1.2 Gbps 2M samples per channel (675-XC-2M) 64M samples per channel (675-XC-64M)
Connectors Number of connectors Number of outputs Output impedance Output type Rise/fall time (10% to 90%) Jitter (rms) Maximum update rate	(Non-standard pinout) 1 8-bits 100 Ω differential LVDS < 1 ns 20 ps 1.2 Gbps 2M samples per channel (675-XC-2M) 64M samples per channel (675-XC-64M) 128M samples per channel (675-XC-128M)
Connectors Number of connectors Number of outputs Output impedance Output type Rise/fall time (10% to 90%) Jitter (rms) Maximum update rate Memory depth	(Non-standard pinout) 1 8-bits 100 Ω differential LVDS < 1 ns 20 ps 1.2 Gbps 2M samples per channel (675-XC-2M) 64M samples per channel (675-XC-64M)
Connectors Number of connectors Number of outputs Output impedance Output type Rise/fall time (10% to 90%) Jitter (rms) Maximum update rate Memory depth 8 bit LVDS to LVTTL Converter Probe	(Non-standard pinout) 1 8-bits 100 Ω differential LVDS < 1 ns 20 ps 1.2 Gbps 2M samples per channel (675-XC-2M) 64M samples per channel (675-XC-64M) 128M samples per channel (675-XC-128M)
Connectors Number of connectors Number of outputs Output impedance Output type Rise/fall time (10% to 90%) Jitter (rms) Maximum update rate Memory depth	(Non-standard pinout) 1 8-bits 100 Ω differential LVDS < 1 ns 20 ps 1.2 Gbps 2M samples per channel (675-XC-2M) 64M samples per channel (675-XC-64M) 128M samples per channel (675-XC-128M)
Connectors Number of connectors Number of outputs Output impedance Output type Rise/fall time (10% to 90%) Jitter (rms) Maximum update rate Memory depth 8 bit LVDS to LVTTL Converter Probe	(Non-standard pinout) 1 8-bits 100 Ω differential LVDS < 1 ns 20 ps 1.2 Gbps 2M samples per channel (675-XC-2M) 64M samples per channel (675-XC-64M) 128M samples per channel (675-XC-128M)
Connectors Number of connectors Number of outputs Output impedance Output type Rise/fall time (10% to 90%) Jitter (rms) Maximum update rate Memory depth 8 bit LVDS to LVTTL Converter Probe	(Non-standard pinout) 1 8-bits 100 Ω differential LVDS < 1 ns 20 ps 1.2 Gbps 2M samples per channel (675-XC-2M) 64M samples per channel (675-XC-64M) 128M samples per channel (675-XC-128M)
Connectors Number of connectors Number of outputs Output impedance Output type Rise/fall time (10% to 90%) Jitter (rms) Maximum update rate Memory depth 8 bit LVDS to LVTTL Converter Probe	(Non-standard pinout) 1 8-bits 100 Ω differential LVDS < 1 ns 20 ps 1.2 Gbps 2M samples per channel (675-XC-2M) 64M samples per channel (675-XC-64M) 128M samples per channel (675-XC-128M)
Connectors Number of connectors Number of outputs Output impedance Output type Rise/fall time (10% to 90%) Jitter (rms) Maximum update rate Memory depth 8 bit LVDS to LVTTL Converter Probe	(Non-standard pinout) 1 8-bits 100 Ω differential LVDS < 1 ns 20 ps 1.2 Gbps 2M samples per channel (675-XC-2M) 64M samples per channel (675-XC-64M) 128M samples per channel (675-XC-128M)
Connectors Number of connectors Number of outputs Output impedance Output type Rise/fall time (10% to 90%) Jitter (rms) Maximum update rate Memory depth 8 bit LVDS to LVTTL Converter Probe (Optional AT-DLL8)	(Non-standard pinout) 1 8-bits 100 Ω differential LVDS < 1 ns 20 ps 1.2 Gbps 2M samples per channel (675-XC-2M) 64M samples per channel (675-XC-64M) 128M samples per channel (675-XC-128M)
Connectors Number of connectors Number of outputs Output impedance Output type Rise/fall time (10% to 90%) Jitter (rms) Maximum update rate Memory depth 8 bit LVDS to LVTTL Converter Probe	(Non-standard pinout) 1 8-bits 100 Ω differential LVDS < 1 ns 20 ps 1.2 Gbps 2M samples per channel (675-XC-2M) 64M samples per channel (675-XC-64M) 128M samples per channel (675-XC-128M)
Connectors Number of connectors Number of outputs Output impedance Output type Rise/fall time (10% to 90%) Jitter (rms) Maximum update rate Memory depth 8 bit LVDS to LVTTL Converter Probe (Optional AT-DLL8)	(Non-standard pinout) 1 8-bits 100 Ω differential LVDS < 1 ns 20 ps 1.2 Gbps 2M samples per channel (675-XC-2M) 64M samples per channel (675-XC-64M) 128M samples per channel (675-XC-128M) where X = 2,4 or 8







Output Voltage	0.8 V to 3.8 V programmable in group of 8 bits
Maximum Update Rate	125 Mbps@0.8V and 400 Mbps@3.6V
Dimensions	W 2in x H 0.9in x D 3in [52mm x 22mm x 76mm]
Input Connector	Proprietary standard
Cable Length	1 meter
Cable Type	Proprietary standard
Proprietary Mini SAS HD to SMA cable (Optional)	1 Topriotally Standard
Output Connector	SMA
Output Type	LVDS
Number of SMA	16 (8 bits)
Cable Type	Proprietary standard
Cable Length	1 meter
Data Pattern Generator (DPG) Spec	rifications
Output Channels	
Connectors	BNC on front panel
Output type	Single-ended
Output Impedance	50 Ω or 5 Ω (low impedance)
General Specifications	
Operating mode	NRZ bitstream Pattern generator
Pattern types	Clock Pattern, Custom Pattern, PRBS pattern
Run Modes	Continuous, modulation, burst (Triggered, Gated, Continuous triggered
Internal Trigger Timer Range Resolution	13.3 ns to 100 s 104 ps
Accuracy	+(0.1% setting + 5 ps)

Ochorai Opcomodiono	
Operating mode	NRZ bitstream Pattern generator
Pattern types	Clock Pattern, Custom Pattern, PRBS pattern
Run Modes	Continuous, modulation, burst (Triggered, Gated, Continuous triggered)
Internal Trigger Timer	
Range	13.3 ns to 100 s
Resolution	104 ps
Accuracy	$\pm (0.1\% \text{ setting + 5 ps})$
Transition Specifications	
Transition peculiarity	Arbitrarily user defined transition shapes Programmable duration for any transition
Transitions types	Arbitrary, predefined
Transitions memory length	64 points
Predefined transition Shapes	Sine, Square, Pulse, Ramp_up, Ramp_down, DC, Sin(x)/x, Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine
Transition duration[0-100%]	1.5ns to Symbol duration for Custom and PRBS pattern
	1.5ns to Period/2 for Clock Pattern
Clock Pattern	
Max clock pattern frequency	150 MHz
Pattern levels	2 levels
Overshoot (1 V _{p-p})	< 2%
Jitter (rms)	< 20 ps
Custom Pattern	
Max custom pattern rate	Up to 300 Mbaud
Pattern levels	2, 3 or 4 levels







Pattern memory Pattern memory Up to 2 MBit (2 levels) Up to 1 MSymbols (3 or 4 levels) Pattern length resolution I bit Min pattern length Overshoot (1 V _{Po}) Vershoot (1 V _{Po}) Pattern length Max PRBS pattern rete Max PRBS pattern rete Pattern levels PRBS 1 yes PRBS 1 yes PRBS 7,9,11,15,23,31 Overshoot (1 V _{Po}) Pattern Modulation Amplitude Modulation (AM) Carrier patterns All types Modulating waveforms Sine, Square, Triangular, Ramp_up, Ramp_down, DC, Sin(x)/x, Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine, Noise, ARB Modulating waveforms All types Modulating waveforms All types Modulating waveforms Sine, Square, Triangular, Ramp_up, Ramp_down, DC, Sin(x)/x, Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine, Noise, ARB Modulating frequency Internal or external Internal rodulating waveforms All types Modulating waveforms All types Modulating frequency Internal retexternal Internal retexternal Modulating frequency Internal retexternal Modulating frequency Internal retexternal Internal retexternal Internal retexternal Modulating frequency Internal: 80 MEz maximum Peak deviation Phase Modulation (PM) Carrier patterns All types Modulation source Internal modulating waveforms All types Modulation source Internal retexternal Internal retexternal Internal retexternal Internal retexternal Internal retexternal Internal retexternal Modulating frequency Internal so plut to 48 MHz External: 8 MHz maximum Peak deviation PM Carrier patterns All types Modulation frequency Internal retexternal Internal retexternal	Predefined custom patterns	Zero, one, clock, counter
Up to 1 MSymbols (3 or 4 levels)	'	
Pattern length resolution 1 bit	rattern memory	. ,
Min pattern length	Pattern length resolution	
Overshoot (1 V _{p0}) < 2%		
PRBS Pattern Up to 300 Mbaud Pattern levels 2 levels PRBS types PRBS -7.9.11,15,23,31 Overshoot (1 V₂₂) < 2%		
Max PRBS pattern rate Up to 300 Mbaud Pattern levels 2 levels Overshoot (1 V _p) < 2%	, , , , , ,	7270
Pattern levels 2 levels PRBS types PRBS -7,9,11,15,23,31 Overshoot (1 V _{p+}) < 2%		Up to 300 Mbaud
PRBS types	•	•
Overshoot (1 V _{Pe}) < 2%		
Pattern Modulation (AM) Carrier patterns		
Amplitude Modulation (AM) Carrier patterns All types Modulation source Internal or external Internal or external Internal modulating waveforms Sine, Square, Triangular, Ramp_up, Ramp_down, DC, Sin(x)/x, Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine, Noise, ARB Modulating frequency Internal: 500 µHz to 48 MHz External: 8 MHz maximum Depth Depth Down to 120.00% Frequency Modulation (FM) Carrier patterns All types Modulation source Internal modulating waveforms Sine, Square, Triangular, Ramp_up, Ramp_down, DC, Sin(x)/x, Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine, Noise, ARB Modulating frequency Internal: 500 µHz to 48 MHz External: 8 MHz maximum Deak deviation DC to 300 MSymbols/s Phase Modulation (PM) Carrier patterns All types Modulating waveforms Sine, Square, Triangular, Ramp_up, Ramp_down, DC, Sin(x)/x, Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine, Noise, ARB Internal modulating waveforms All types Modulation source Internal modulating waveforms Sine, Square, Triangular, Ramp_up, Ramp_down, DC, Sin(x)/x, Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine, Noise, ARB Modulating frequency Internal: 500 µHz to 48 MHz External: 8 MHz maximum Peak deviation range O' to 360' Frequency Shift Keying (FSK) Carrier patterns All types Modulation source Internal modulating waveforms Square Key rate Internal: 8 MHz maximum Hope Symbol Rate Internal: 8 MHz maximum Hope Symbol Rate All types Phase Shift Keying (FSK) Carrier patterns All types Phase Shift Keying (FSK) Carrier patterns All types	X 117	~ Z 70
Carrier patterns		
Internal modulating waveforms Sine, Square, Triangular, Ramp_up, Ramp_down, DC, Sin(x)/x, Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine, Noise, ARB	. ,	
Internal modulating waveforms Sine, Square, Triangular, Ramp_up, Ramp_down, DC, Sin(x)/x, Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine, Noise, ARB Modulating frequency Internal: 500 µHz to 48 MHz External: 8 MHz maximum Depth 0.00% to 120.00% Frequency Modulation (FM) Carrier patterns All types Modulation source Internal or external Internal modulating waveforms Sine, Square, Triangular, Ramp_up, Ramp_down, DC, Sin(x)/x, Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine, Noise, ARB Modulating frequency Internal: 500 µHz to 48 MHz External: 8 MHz maximum Peak deviation Phase Modulation (PM) Carrier patterns All types Modulating waveforms All types Modulating waveforms Sine, Square, Triangular, Ramp_up, Ramp_down, DC, Sin(x)/x, Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine, Noise, ARB Modulation source Internal or external Internal modulating waveforms Sine, Square, Triangular, Ramp_up, Ramp_down, DC, Sin(x)/x, Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine, Noise, ARB Modulating frequency Internal: 500 µHz to 48 MHz External: 8 MHz maximum Peak deviation range 0° to 360° Frequency Shift Keying (FSK) Carrier patterns All types Internal or external Internal modulating waveforms Square Key rate Internal: 500 µHz to 48 MHz External: 8 MHz maximum Hope Symbol Rate Internal: 500 µHz to 48 MHz External: 8 MHz maximum Hope Symbol Rate Iusymbols/s to 300 MSymbols/s for Custom and PRBS pattern 1uHz to 150 MHz for Clock pattern	•	• • • • • • • • • • • • • • • • • • • •
Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine, Noise, ARB Modulating frequency Internal: 500 µHz to 48 MHz External: 8 MHz maximum Depth 0.00% to 120.00% Frequency Modulation (FM) Carrier patterns All types Modulation source Internal or external Internal modulating waveforms Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine, Noise, ARB Modulating frequency Internal or external Rise, Exponential Decay, Haversine, Noise, ARB Modulating frequency Dc to 300 MSymbols/s Phase Modulation (PM) Carrier patterns All types Modulating waveforms Sine, Square, Triangular, Ramp_up, Ramp_down, DC, Sin(x)/X, Caussian, Lorentz, Exponential Rise, Exponential Decay, Haversine, Noise, ARB Modulation source Internal or external Internal modulating waveforms Sine, Square, Triangular, Ramp_up, Ramp_down, DC, Sin(x)/X, Caussian, Lorentz, Exponential Rise, Exponential Decay, Haversine, Noise, ARB Modulating frequency Internal: 500 µHz to 48 MHz External: 8 MHz maximum Peak deviation range Or to 360° Frequency Shift Keying (FSK) Carrier patterns All types Modulation source Internal or external Internal modulating waveforms Square Key rate Internal: 500 µHz to 48 MHz External: 8 MHz maximum Hope Symbol Rate Internal: 500 µHz to 48 MHz External: 8 MHz maximum Hope Symbol Rate Internal: 500 µHz to 48 MHz External: 8 MHz maximum Hope Symbol Rate Internal: 500 µHz to 48 MHz External: 8 MHz maximum Hope Symbol Rate Internal: 500 µHz to 48 MHz External: 8 MHz maximum Hope Symbol Rate Internal: 500 µHz to 48 MHz External: 8 MHz maximum Hope Symbol Rate Internal: 500 µHz to 6 Lock pattern Under to 1500 MHz for Clock pattern		
External: 8 MHz maximum Depth 0,00% to 120,00% Frequency Modulation (FM) Carrier patterns All types Internal or external Internal modulating waveforms Modulating frequency Internal: 500 µHz to 48 MHz External: 8 MHz maximum Peak deviation PM) Carrier patterns All types Modulating waveforms Internal or external Internal modulating waveforms Peak deviation Post of the state of the sta	Internal modulating waveforms	Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine,
Depth 0.00% to 120.00% Frequency Modulation (FM) Carrier patterns All types Modulation source Internal or external Internal modulating waveforms Sine, Square, Triangular, Ramp_up, Ramp_down, DC, Sin(x)/x, Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine, Noise, ARB Modulating frequency Internal: 500 µHz to 48 MHz External: 8 MHz maximum Peak deviation DC to 300 MSymbols/s Phase Modulation (PM) Carrier patterns All types Modulating waveforms Sine, Square, Triangular, Ramp_up, Ramp_down, DC, Sin(x)/x, Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine, Noise, ARB Modulating waveforms Sine, Square, Triangular, Ramp_up, Ramp_down, DC, Sin(x)/x, Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine, Noise, ARB Modulating frequency Internal: 500 µHz to 48 MHz External: 8 MHz maximum Peak deviation range 0° to 360° Frequency Shift Keying (FSK) Carrier patterns All types Modulation source Internal or external Internal modulating waveforms Square Key rate Internal: 500 µHz to 48 MHz External: 8 MHz maximum Hope Symbol Rate Internal: 500 µHz to 48 MHz External: 8 MHz maximum Hope Symbol Rate 1uSymbols/s to 300 MSymbols/s for Custom and PRBS pattern 1 uHz to 150 MHz for Clock pattern 1 uHz to 150 MHz for C	Modulating frequency	Internal: 500 µHz to 48 MHz
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Internal modulating waveforms	Square	
Key rate	Internal: 500 µHz to 48 MHz	
	External: 8 MHz maximum	
Hope phase	0° to +360°	
Number of keys	2	
Burst		
Patterns	All types	
Туре	Block mode or Bit mode	
Burst count	1 to 4,294,967,295 cycles or Infinite	
Auxiliary Input and Output Characteristics		

Auxiliary Input and Output Characteristics Marker Output	
Number of Connectors	1, 2 or 4
Output Impedance	50 Ω
Output level (into 50 Ω)	
Amplitude	1 V to 2.5 V
Resolution	10 mV
Accuracy	±(2% setting + 10 mV)
Rise/fall time (10% to 90%, 2.5 V _{p-p})	<700 ps
Jitter (rms)	20 ps
Marker out to analog channel skew	
Range	AFG and DPG Mode: 0 to 14s in Continuous Mode
	0 to 3 us in Triggered Mode
	True Arb Mode: 0 to 3µs
Resolution	AFG and DPG Mode: 39 ps
	True Arb Mode: 78 ps,
Accuracy	±(1% of setting + 140 ps)
Initial skew	< 1 ns
Trigger/Gate Inputs	
Connector	BNC on the Front Panel
Input Impedance	50Ω/1 kΩ

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Connector	BNC on the Front Panel
Input Impedance	50Ω/1 kΩ
Slope/Polarity	Positive or negative or both
Input Damage Level	< -15 V or > +15 V
Threshold Control Level	-10 V to 10 V
Resolution	50 mv
Threshold Control Accuracy	±(10% of setting + 0.2 V)
Input Voltage Swing	0.5 V _{p-p} minimum
Minimum Pulse Width (1 V _{p-p})	3 ns
Initial trigger delay to Analog Output	AFG: < 360 ns (< 420 ns in triggered sweep mode,AFG only)
	True Arb mode: < 240 * DAC clock period + 32 ns
	DPG mode: < 370 ns
Trigger In to output jitter	AFG and DPG mode: < 40 ps
	True Arb mode: 0.29*DAC clock period
Maximum Frequency	AFG and DPG mode: 65 MTps on Rising/Falling Edge
	80 MTps on Both Edges
	True Arb mode: 42.5 MTps
	where MTps = Mega Transitions per second





Reference clock input	
Connector type	SMA on rear panel
Input impedance	50 Ω, AC coupled
Input voltage range	-4 dBm to 11 dBm sine or square wave
	(Rise time T10-90 <1 ns and Duty Cycle from 40% to 60%)
Damage level	+14 dBm
Frequency range	5 MHz to 100 MHz
Reference clock output	- I am
Connector type	SMA on rear panel
Output impedance	50 Ω, AC coupled
Frequency	10 MHz
Accuracy	± 2.0 ppm
Aging	± 1.0 ppm/year
Amplitude	1.65 V
Jitter (rms)	< 20 ps
External Modulation input	
Connector type	SMA on rear panel
Input impedance	>2 MΩ
Number of inputs	1
Bandwidth	8 MHz with 40 MS/s sampling rate
Input voltage range	-0.5V to +0.5V
Vertical resolution	8-bit
Power	
Source Voltage and Frequency	100 to 240 VAC ±10% @ 45-66 Hz
Maximum power consumption	150W
Environmental Characteristics	
Temperature (operating)	+41 °F to 104 °F [+5 °C to +40 °C]
Temperature (non-operating)	-4 °F to 140 °F [-20 °C to +60 °C]
Humidity (operating)	5% to 80% relative humidity with a maximum wet bulb temperature of 84°F at or below +104°F, (upper limit de–rates to 20.6% relative humidity at +104°F). Non-condensing.
Humidity (non-operating)	5% to 95% relative humidity with a maximum wet bulb temperature of 104°F at or below +140°F, upper limit de–rates to 29.8% relative humidity at +140°F. Non-condensing.
Altitude (operating)	9,842 feet (3,000 meters) maximum at or below 77°F
Altitude (non-operating)	39,370 feet (12,000 meters) maximum
EMC and Safety	
Compliance	CE compliant
Safety	EN61010-1
Main Standards	EN 61326-1:2013 – Electrical equipment for measurement, control and laboratory use – EMC requirements – Part 1: General requirements
Immunity	EN 61326-1:2013







System Specifications	
Display	7", 1024x600, capacitive touch LCD
Operative System	Windows 10
External Dimensions	W 17.6 in – H 5.4 in – D 12.6 in (3U 19" rackmount) (445 mm – 135 mm – 320 mm)
Weight	21 lbs (675-2C) – 23 lbs (675-4C) – 26.5 lbs (675-8C)
Front panel connectors	CH1 to CH8 OUTPUT (BNC)
	MARKER OUT 1 to 4 (BNC)
	TRIGGER IN (BNC)
Rear panel connectors	Ref Clk In (SMA) Ref Clk Out (SMA) Ext Mod In (SMA) External Monitor ports (one or more) DIGITAL POD A[70] (675-2C/4C/8C) DIGITAL POD B[70] (675-4C/8C) DIGITAL POD C[70] (675-8C) DIGITAL POD D[70] (675-8C) 1 USB 2.0 ports or more Ethernet port (10/100/1000BaseT Ethernet, RJ45 port) 2 PS/2 keyboard and mouse ports
Hard Disk	32 GB SSD or better
Processor	Intel® Celeron J1900, 2 GHz (or better)
Processor Memory	4 GB or better